Synthesis and characterisation of the new oxyselenide Bi₂YO₄Cu₂Se₂⁺

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In this communication we report the synthesis, structure and preliminary characterisation of $Bi_2LnO_4Cu_2Se_2$ (Ln = Y, Gd, Sm, Nd, La) phases; these materials are members of a new family of layered oxychalcogenides.

The range of technologically important applications of mixed metal oxides and mixed metal chalcogenides is vast. They have been exploited (inter alia) for their conductivity, magnetic, catalytic, optical, energy storage and structural properties. In contrast, the amount of work on oxychalcogenides, materials that contain both oxide and chalcogenide anions, is relatively sparse. This is, of course, partially due to the propensity of such materials to decompose to species containing oxyanions $(SO_4^{2-}, SO_3^{2-}, etc.)$ in which the chalcogen has been oxidised. There are, however, a number of such phases known ranging from simple species such as ZrOS1 and natural minerals such as kermesite and sarabauite (Sb₂OS₂ and CaSb₁₀S₆O₁₀);^{2,3} threedimensional phases such as La2Ta2S2O84 and LaCrOS2;5 layered materials such as Na₂Cu₄OSe₂,⁶ (LaO)₄Sn₂S₆⁷ and Sr₂Cu₂CoO₂S₂⁸ and very recently Ruddlesden–Popper phases such as $Ln_2Ti_2O_5S_2$ (Ln = Pr, Nd, Sm–Er, Y) and their alkali metal intercalates.9-11 Such phases are of interest in that they offer potential control of material properties via the anion rather than the cation sublattice.

In this communication we report the synthesis and structural characterisation of a new family of layered oxyselenides of general formula $Bi_2LnO_4Cu_2Se_2$. These phases were targeted using a simple 'building block' strategy^{12,13} and were anticipated to contain the stable [Cu_2Se_2]ⁿ building block and oxide layers related to those in other oxide/mixed anion phases.

Bi₂LnO₄Cu₂Se₂ phases were prepared by heating a stoichiometric mixture of Ln₂O₃, Bi₂O₃, Cu, Bi and Se in an evacuated sealed silica ampoule to a temperature of 850 °C for 24 h. Lower temperatures resulted in the predominance of the stable BiOCuSe,^{14,15} whilst higher temperatures or longer reaction times led to higher impurity levels (presumably due to side reactions with the silica ampoule) and sample decomposition.

Initial inspection of laboratory powder X-ray diffraction data of Bi₂YO₄Cu₂Se₂ suggested that the material had the structure type anticipated. This was confirmed by Rietveld refinement of laboratory X-ray powder data and time of flight neutron diffraction data collected on the SEPD diffractometer at the Intense Pulsed Neutron Source (IPNS) at the Argonne National Laboratory, USA. Refinement results are shown in Fig. 1 and Table 1.[‡] The structure of Bi₂YO₄Cu₂Se₂ is shown in Fig. 2. It has space group *I*4/*mmm* with a = b = 3.864 Å, c = 24.428 Å and can be described as formally containing layers of [Cu₂Se₂]⁻ Cu centred edge sharing tetrahedra interspersed with [Bi₂YO₄]⁺ oxide layers. Similar [Cu₂Se₂]^{*n*} blocks are found in materials such as TlCu₂Se₂, BiOCuSe^{14,15} and others. We note that if one assumes formal oxidation states of Cu¹⁺ and Se²⁻ there must be holes present in the valence band.¹⁶ The oxide slabs contain Y in a pseudo-cubic coordination environment (8 × O at 2.378 Å) with a c/a ratio of the YO₈ unit of 1.015. Bi adopts a coordination environment typical of a lone pair cation with four short bonds to oxygen (4 × 2.232 Å) and four longer bonds to Se (4 × 3.431 Å) of the Cu₂Se₂ layers. A similar oxide building block can be found in Bi₂LaO₄Cl.¹⁷

Other members of this family with Ln = Y, Gd, Sm, Nd and La have been prepared and characterised. Their unit cell



Fig. 1 Results of (a) neutron and (b) X-ray Rietveld refinements. Red points show the observed data, blue line the calculated pattern and the lower pink line the difference curve. Vertical tick marks show positions of allowed reflections. Minor impurity regions have been excluded from neutron data.

Table 1 Fractional atomic coordinates determined by combined refinement

 of X-ray and neutron diffraction data^a

Atom	x/a	y/b	z/c	$100 U_{\rm iso}/{\rm \AA^2}$
Bi	0.5	0.5	0.89748(6)	0.87(3)
Y	0.5	0.5	0.5	0.45(5)
0	0.0	0.5	0.94322(8)	0.94(5)
Cu	0.0	0.5	0.25	1.39(4)
Se	0.5	0.5	0.31254(7)	1.24(4)
^a Space g	roup I4/mn	um, 293 K, a =	= b = 3.86463(3), c	= 24.428(4) Å.

[†] Electronic supplementary information (ESI) available: fractional atomic coordinates from Rietveld refinement of Bi₂Ln₄O₄Cu₄Se₂ phases. See http://www.rsc.org/suppdata/cc/b2/b200892k/



Fig. 2 Structure of ${\rm Bi}_2{\rm YO}_4{\rm Cu}_2{\rm Se}_2$ in ball and stick and polyhedral representations.

Table 2 Cell parameters of $Bi_2 LnO_4 Cu_2 Se_2$ phases determined by X-ray diffraction data

Atom	а	С	V/Å ³
Y	3.8631(5)	24.4227(5)	364.47(1)
Gd	3.88631(8)	24.4535(6)	369.33(1)
Sm	3.89976(7)	24.4620(6)	372.02(1)
Nd	3.91795(10)	24.5001(8)	376.09(2)
La	3.95319(29)	24.6314(23)	384.93(5)

parameters are included in Table 2§ and show the expected trends with Ln radius.

Preliminary measurements of electrical resistivity were carried out on pellets of Bi₂YO₄Cu₂Se₂ using evaporated In contacts in a conventional four-probe arrangement. Current-voltage measurements confirmed that the contacts were ohmic. Resistivity (ρ)-temperature (*T*) characteristics were measured under constant current conditions over the temperature range 77–300 K using an Oxford Instruments DN107 liquid nitrogen crysostat controlled by an Oxford Instruments ITC4 controller. Room temperature values of resistivity were ~2 × 10⁻² Ω cm and were found to vary linearly with temperature, implying that conduction was essentially metallic in character. The temperature coefficient was ~ 4 × 10⁻⁵ Ω cm K⁻¹.

Further studies on the properties and chemistry of this family of materials are in progress.

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Notes and references

‡ Neutron diffraction data were recorded on a 4.9 g sample on the SEPD diffractometer of the Intense Pulsed Neutron Source at Argonne National Laboratory. Data were collected and analysed over a time of flight range of 3-30 ms (d = 0.47-4.01 Å). This sample contained small impurities (not present in smaller scale syntheses) which were excluded from the refinement. X-Ray diffraction data were collected from $10-120^{\circ} 2\theta$ on a Siemens d5000 diffractometer equipped with a graphite diffracted beam monochromator. A step size of 0.02° and a time per step of 10 s were used. To obtain high precision fractional coordinates a combined refinement of neutron and X-ray data was performed in the GSAS software suite.¹⁸ A total of 33 variables were refined (2 scale factors, 2 cell parameters, 3 fractional coordinates, 5 temperature factors, 8 profile coefficients, 6 background terms per phase). Final agreement factors were $\chi^2 = 3.0$, $R(F^2) =$ 9.78/7.74%, $wR_p = 11.09/8.23\%$ (X-ray/neutron). Fig. 1 contains X-ray data of a higher purity sample refined on the same structural model that gave $\chi^2 = 2.0, R(F^2) = 8.69\%, wR_p = 9.85\%.$

§ Cell parameters were determined by Rietveld refinement of data collected from $5-120^{\circ} 2\theta$ with a step size of 0.02° and a collection time per step of 9 s. Fractional coordinates derived from these refinements have been deposited as ESI.†

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